



BSS84W

P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

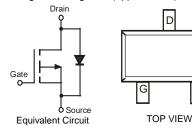
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)



SOT-323



Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Units	
Drain-Source Voltage		V_{DSS}	-50	V
Drain-Gate Voltage (Note 1)		V_{DGR}	-50	V
Gate-Source Voltage	Continuous	V _{GSS}	±20	V
Drain Current (Note 1)	Continuous	I _D	-130	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 1)	P_d	200	mW
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	T_j , T_{STG}	-55 to +150	°C

Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV _{DSS}	-50	-75		٧	$V_{GS} = 0V, I_D = -250\mu A$
		_		-15	μΑ	$V_{DS} = -50V$, $V_{GS} = 0V$, $T_{J} = 25^{\circ}C$
Zero Gate Voltage Drain Current	I_{DSS}			-60		$V_{DS} = -50V$, $V_{GS} = 0V$, $T_{J} = 125$ °C
			_	-100	nA	$V_{DS} = -25V$, $V_{GS} = 0V$, $T_{J} = 25^{\circ}C$
Gate-Body Leakage	I _{GSS}		-	±10	nΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V _{GS(th)}	-0.8	-1.6	-2.0	V	$V_{DS} = V_{GS}$, $I_D = -1mA$
Static Drain-Source On-Resistance	R _{DS (ON)}	_	6	10	Ω	$V_{GS} = -5V, I_D = -0.100A$
Forward Transconductance	g _{FS}	.05	_	_	S	$V_{DS} = -25V, I_D = -0.1A$
DYNAMIC CHARACTERISTICS						
Input Capacitance	Ciss	_	_	45	pF	
Output Capacitance	Coss	_	_	25	pF	$V_{DS} = -25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	Crss	_	_	12	pF	
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{D(ON)}		10	_	ns	$V_{DD} = -30V, I_D = -0.27A,$
Turn-Off Delay Time	t _{D(OFF)}	_	18	_	ns	$R_{GEN} = 50\Omega$, $V_{GS} = -10V$

Notes:

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.
 - Short duration pulse test used to minimize self-heating effect.

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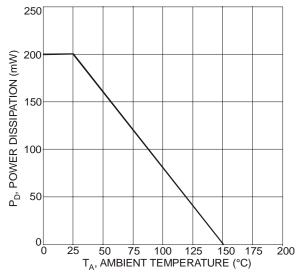
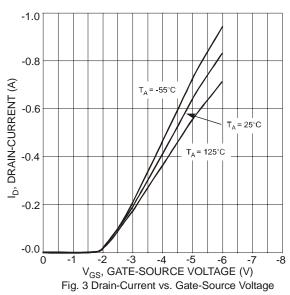
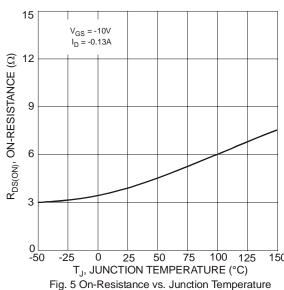


Fig. 1 Max Power Dissipation vs. Ambient Temperature





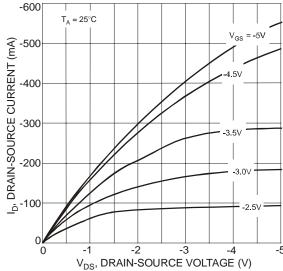


Fig. 2 Drain-Source Current vs.Drain-Source Voltage

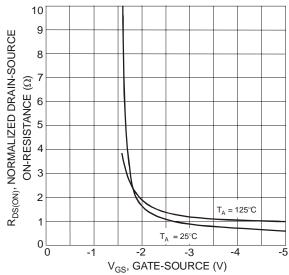


Fig. 4 On-Resistance vs. Gate-Source Voltage

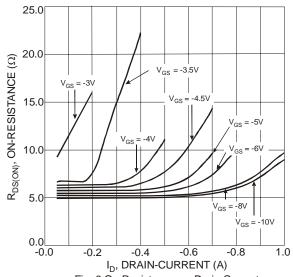


Fig. 6 On-Resistance vs. Drain-Current

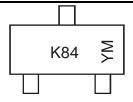


Ordering Information (Notes 4 and 6)

Part Number	Case	Packaging
BSS84W-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

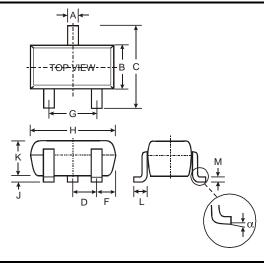


K84 = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

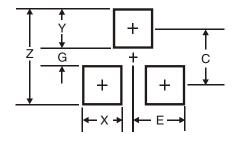
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Χ	Υ	Z
Month	Jan	Fe	b I	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Ос	t I	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		N	D

Package Outline Dimensions



SOT-323						
Dim	Min	Max				
Α	0.25	0.40				
В	1.15	1.35				
C	2.00	2.20				
D	0.65 Nominal					
F	0.30	0.40				
G	1.20	1.40				
H	1.80	2.20				
7	0.0 0.10					
K	0.90	1.00				
٦	0.25	0.40				
М	0.10	0.18				
α	0°	8°				
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
G	1.0
Х	0.7
Υ	0.9
С	1.9
Е	0.65

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